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US PATENT DOCUMENTS					
					Pages, Columns,
			Publication		Lines, Where Relevant
Examiner	Cite	USP Document	or Issue Date	Name of Patentee or Applicant	Passages or Relevant
Initial *	No '	Number	MM-DD-YYYY	of cited Document	Figures Appear

FOREIGN PATENT DOCUMENTS						
		Foreign Patent Document			Pages, Columns, Lines,	
Examiner	Cite	Country Code/Number/Kind Code	Publication Date	Name of Patentee or Applicant of	Where Relevant Passages	
Initials*	No '	(if known)	MM-DD-YYYY	cited Document	or Relevant Figures Appear	L.

	OTHER DOCUMENTS NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T²	
		CHU, CHEN F., et al., "Comparison of p-Side Down and p-Side Up GaN Light-		
	1 1 1 1 1 1	Emitting Diodes Fabricated by Laser Lift-Off", Japan Journal of Applied Physics, Vol.		
		42, (02/15/2003), 147-150		
		LI, W.H., et al., "Electrochemical deposition of Copper on patterned Cu/Ta(N)SiO2		
	1 1 1 1 1 1	surfaces for super filling of sub-micron features", Journal of Applied Electrochemistry,		
		Vol. 31, (2001), 1395-1397		

11/05/2009 /Hoai Pham/ **EXAMINER** DATE CONSIDERED